IOTOROLA

The RF Line **Wideband Linear Amplifiers**

. . . designed for amplifier applications in 50 to 100 ohm systems requiring wide bandwidth, low noise and low distortion. This hybrid provides excellent gain stability with temperature and linear amplification as a result of the push-pull circuit design.

• Specified Characteristics at V_{CC} = 24 V, T_{C} = 25°C:

Frequency Range — 5 to 200 MHz

Output Power — 800 mW Typ @ 1 dB Compression, f = 200 MHz

Power Gain — 34.5 dB Typ @ f = 100 MHz

PEP — 800 mW Typ @ -32 dB IMD

Noise Figure — 4.7 dB Typ @ f = 200 MHz

ITO — 46 dBm @ f = 200 MHz

- All Gold Metallization for Improved Reliability
- Unconditional Stability Under All Load Conditions

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
DC Supply Voltage	V _{CC}	28	Vdc
RF Power Input	P _{in}	+5	dBm
Operating Case Temperature Range	T _C	-20 to +100	°C
Storage Temperature Range	T _{stg}	-40 to +100	°C

CA2830C

34.5 dB 5-200 MHz 800 mWATT **WIDEBAND LINEAR AMPLIFIERS**



(CA)

ELECTRICAL CHARACTERISTICS (T_C = 25°C, V_{CC} = 24 V, 50 Ω system unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
Frequency Range	BW	5	_	200	MHz
Gain Flatness (f = 5–200 MHz)	_	_	±0.5	±1	dB
Power Gain (f = 100 MHz)	P_{G}	33.5	34.5	35.5	dB
Noise Figure, Broadband (f = 200 MHz)	NF	_	4.7	5.5	dB
Power Output — 1 dB Compression (f = 5–200 MHz)	P _{o 1dB}	630	800	_	mW
Power Output — 1 dB Compression (f = 5–200 MHz, V _{CC} = 28 V)	P _{o 1dB}	1000	1260	_	mW
Third Order Intercept (See Figure 10, f ₁ = 200 MHz)	ITO	44	46	_	dBm
Input/Output VSWR (f = 5-200 MHz)	VSWR	_	1.5:1	2:1	_
Second Harmonic Distortion (Tone at 100 mW, f _{2H} = 150 MHz)	d _{so}	_	-60	-50	dB
Peak Envelope Power (Two Tone Distortion Test — See Figure 10) (f = 5–200 MHz @ –32 dB IMD)	PEP	600	800	_	mW
Supply Current	I _{CC}	270	300	330	mA



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TYPICAL CHARACTERISTICS

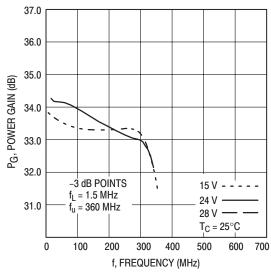


Figure 1. Power Gain versus Frequency

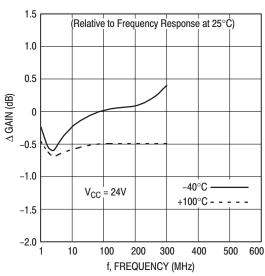


Figure 2. Relative Power Gain versus Temperature

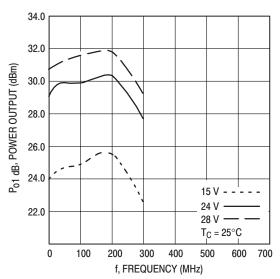


Figure 3. 1 dB Gain Compression versus Voltage

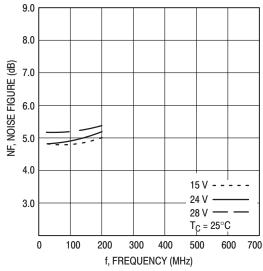


Figure 4. Noise Figure versus Voltage

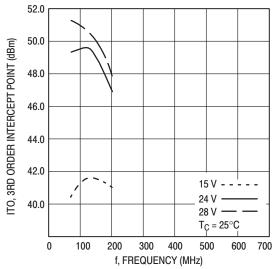


Figure 5. Third Order Intercept versus Voltage

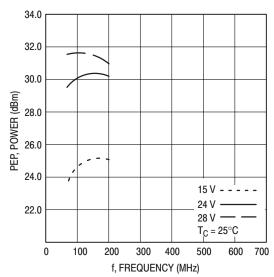
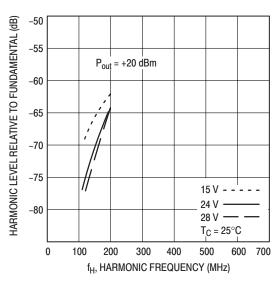


Figure 6. Peak Envelope Power versus Voltage



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3 DELAY (ns) 2 0 $T_C = 25^{\circ}C$ $V_{CC} = 24 V$ -1 -2 200 600 700 0 100 300 400 500 f, FREQUENCY (MHz)

Figure 7. Second Harmonic Distortion versus Voltage

Figure 8. Group Delay versus Frequency

Biased at 24 Volts

 $T = 25^{\circ}C$ $Zo = 50\Omega$

Frequency	S11		S21		S12		S22	
(MHz)	Mag	Ang	Mag	Ang	Mag	Ang	Mag	Ang
5	-18.3	66.2	34.6	15.2	-47.0	17.7	-9.8	87.4
10	-19.3	45.5	34.6	-0.6	-47.0	2.3	-14.5	76.8
50	-15.6	35.0	34.2	-56.7	-47.5	-30.3	-12.6	45.0
100	-13.2	34.4	33.9	-114	-47.9	-62.9	-10.8	10.7
200	-11.1	30.1	33.5	134	-48.3	-128	-14.9	-42.6

Magnitude in dB, Phase Angle in degrees.

Table 1. S-Parameters

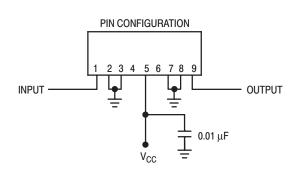
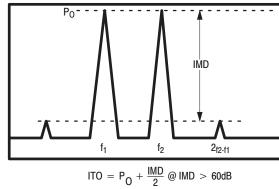


Figure 9. External Connections



 $PEP = 4X P_0 @ IMD = -32dB$

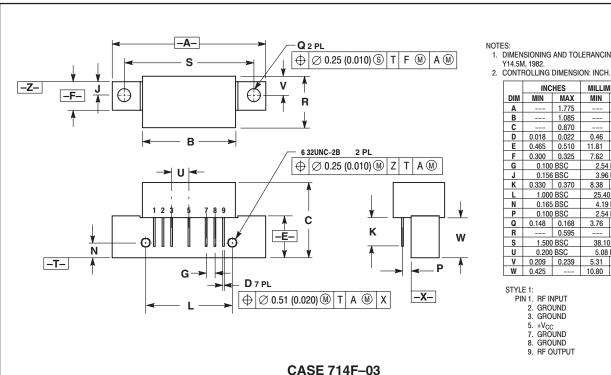
Figure 10. Intermodulation Test

ARCHIVE INFORMATION



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PACKAGE DIMENSIONS



- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI

	INC	HES	MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α		1.775		45.08	
В		1.085		27.56	
С		0.870		22.10	
D	0.018	0.022	0.46	0.56	
Е	0.465	0.510	11.81	12.95	
F	0.300	0.325	7.62	8.25	
G	0.100	BSC	2.54 BSC		
J	0.156 BSC		3.96 BSC		
K	0.330	0.370	8.38	9.40	
L	1.000	BSC	25.40 BSC		
N	0.165	BSC	4.19 BSC		
Р	0.100	BSC	2.54 BSC		
Q	0.148	0.168	3.76	4.27	
R		0.595		15.11	
S	1.500 BSC		38.10 BSC		
U	0.200 BSC		5.08 BSC		
٧	0.209	0.239	5.31	6.07	
W	0.425		10.80		

- PIN 1. RF INPUT

 - 9. RF OUTPUT

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Mfax™: RMFAX0@email.sps.mot.com - TOUCHTONE 602-244-6609

JAPAN: Nippon Motorola Ltd.: SPD, Strategic Planning Office, 4-32-1, Nishi-Gotanda, Shinagawa-ku, Tokyo 141, Japan. 81-3-5487-8488

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INTERNET: http://motorola.com/sps